NSN 5961-01-188-2593



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-188-2593 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 5.0 emitter to base voltage, static, collector open and 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 120.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 unthreaded hole and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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